

WIDEBAND HIGH GAIN POWER AMPLIFIER MODULE, 2 - 20 GHz

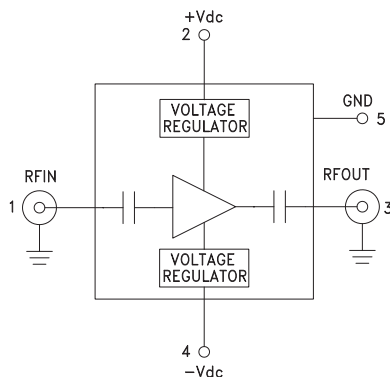


Typical Applications

The HMC-C026 Wideband PA is ideal for:

- Telecom Infrastructure
- Microwave Radio & VSAT
- Military & Space
- Test Instrumentation
- Fiber Optics

Functional Diagram



Features

- Gain: 31 dB @ 6 GHz
- P1dB Output Power: +26 dBm @ 6 GHz
- Noise Figure: 2.5 dB @ 8 GHz
- Spurious-Free Operation
- Regulated Supply and Bias Sequencing
- Hermetically Sealed Module
- Field Replaceable SMA connectors
- 55 °C to +85 °C Operating Temperature

General Description

The HMC-C026 is a GaAs MMIC pHEMT Distributed Power Amplifier in a miniature, hermetic module with replaceable SMA connectors which operates between 2 and 20 GHz. The amplifier provides 31 dB of gain, 2.5 dB noise figure, +30 dBm output IP3 and up to +26 dBm of output power at 1 dB gain compression. The wideband amplifier I/Os are internally matched to 50 Ohms and are DC blocked making the HMC-C026 ideal for EW, ECM RADAR and test equipment applications. Integrated voltage regulators allow for flexible biasing of both the negative and positive supply pins, while internal bias sequencing circuitry assures robust operation.

Electrical Specifications, $T_A = +25^\circ\text{C}$, $+V_{dc} = +11\text{V to } +16\text{V}$, $-V_{dc} = -3\text{V to } -12\text{V}$

| Parameter | Min. | Typ. | Max. | Min. | Typ. | Max. | Min. | Typ. | Max. | Min. | Typ. | Max. | Units |
|--|-------|-------|------|--------|-------|------|---------|------|------|---------|------|------|-------|
| Frequency Range | 2 - 6 | | | 6 - 12 | | | 12 - 16 | | | 16 - 20 | | | GHz |
| Gain | 28 | 31 | | 26 | 29 | | 24 | 27 | | 19 | 22 | | dB |
| Gain Flatness | | ±0.25 | | | ±0.75 | | | ±1.0 | | | ±2.0 | | dB |
| Gain Variation Over Temperature | | 0.03 | 0.04 | | 0.03 | 0.04 | | 0.03 | 0.04 | | 0.03 | 0.04 | dB/°C |
| Noise Figure | | 3.0 | 5.0 | | 2.5 | 3.5 | | 3.0 | 4.0 | | 3.5 | 5.0 | dB |
| Input Return Loss | | 15 | | | 15 | | | 13 | | | 10 | | dB |
| Output Return Loss | | 15 | | | 15 | | | 10 | | | 8 | | dB |
| Output Power for 1 dB Compression (P1dB) | 23 | 26 | | 22.5 | 25.5 | | 20 | 24 | | 18 | 21 | | dBm |
| Saturated Output Power (P _{sat}) | | 27.5 | | | 27 | | | 25 | | | 23 | | dBm |
| Output Third Order Intercept (IP3) | | 33 | | | 30 | | | 27 | | | 24 | | dBm |
| Positive Supply Current (+IDC) | | 400 | 450 | | 400 | 450 | | 400 | 450 | | 400 | 450 | mA |
| Negative Supply Current (-IDC) | | 3.2 | 5 | | 3.2 | 5 | | 3.2 | 5 | | 3.2 | 5 | mA |

Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners.

For price, delivery, and to place orders: Analog Devices, Inc., One Technology Way, P.O. Box 9106, Norwood, MA 02062-9106
Phone: 781-329-4700 • Order online at www.analog.com
Application Support: Phone: 1-800-ANALOG-D

HMC-C026* PRODUCT PAGE QUICK LINKS

Last Content Update: 02/23/2017

COMPARABLE PARTS

View a parametric search of comparable parts.

DOCUMENTATION

Application Notes

- AN-1363: Meeting Biasing Requirements of Externally Biased RF/Microwave Amplifiers with Active Bias Controllers

Data Sheet

- HMC-C026 Data Sheet

TOOLS AND SIMULATIONS

- HMC-C026 S-Parameter

DESIGN RESOURCES

- HMC-C026 Material Declaration
- PCN-PDN Information
- Quality And Reliability
- Symbols and Footprints

DISCUSSIONS

View all HMC-C026 EngineerZone Discussions.

SAMPLE AND BUY

Visit the product page to see pricing options.

TECHNICAL SUPPORT

Submit a technical question or find your regional support number.

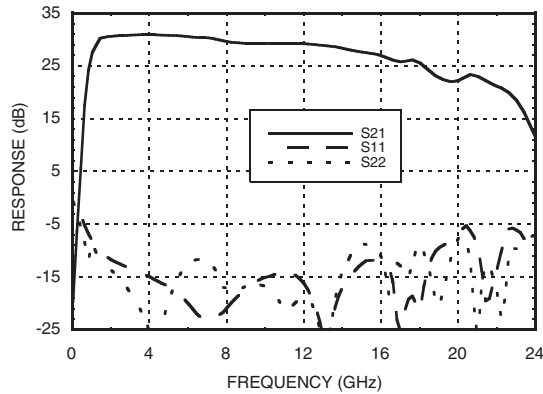
DOCUMENT FEEDBACK

Submit feedback for this data sheet.

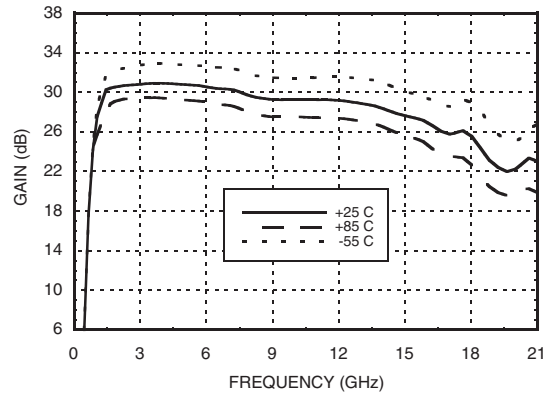


**WIDEBAND HIGH GAIN POWER AMPLIFIER
MODULE, 2 - 20 GHz**

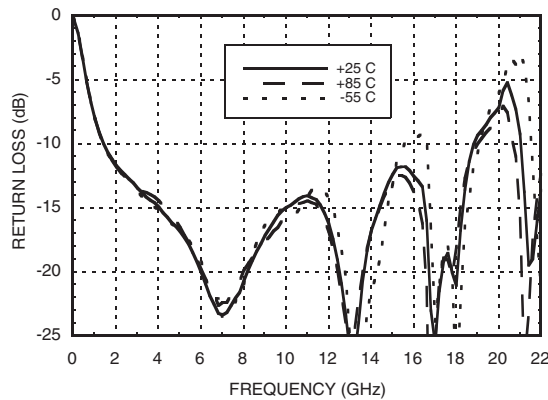
Gain & Return Loss



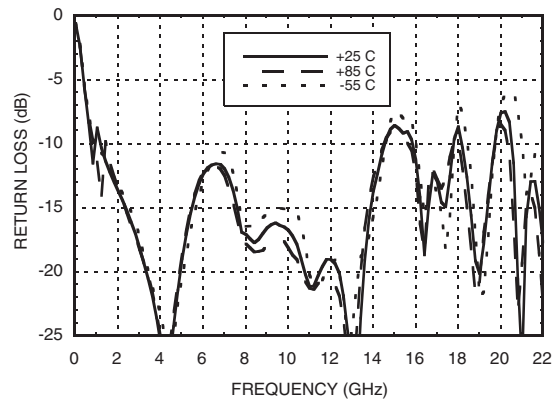
Gain vs. Temperature



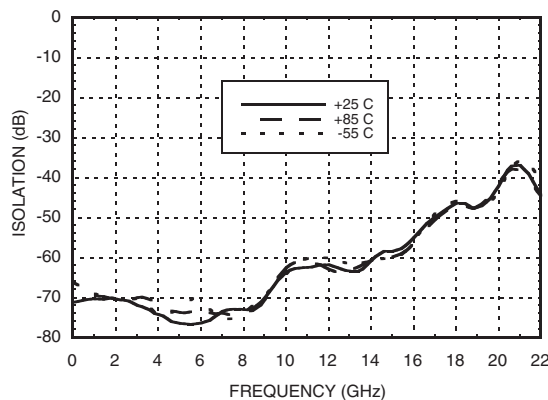
Input Return Loss vs. Temperature



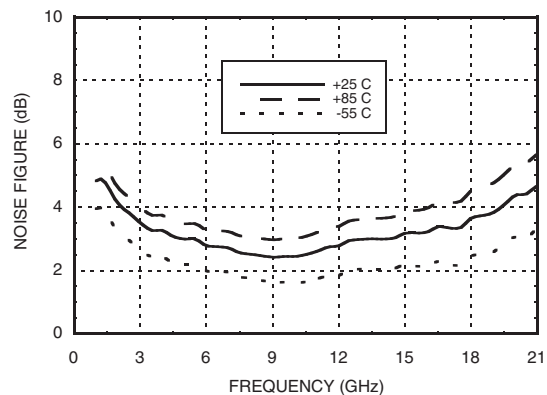
Output Return Loss vs. Temperature



Reverse Isolation vs. Temperature



Noise Figure vs. Temperature



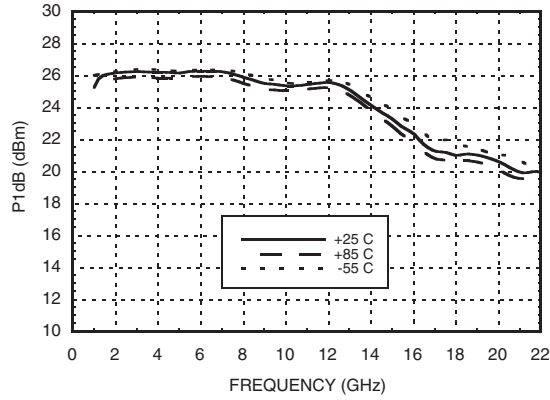
Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners.

For price, delivery, and to place orders: Analog Devices, Inc., One Technology Way, P.O. Box 9106, Norwood, MA 02062-9106 Phone: 781-329-4700 • Order online at www.analog.com Application Support: Phone: 1-800-ANALOG-D

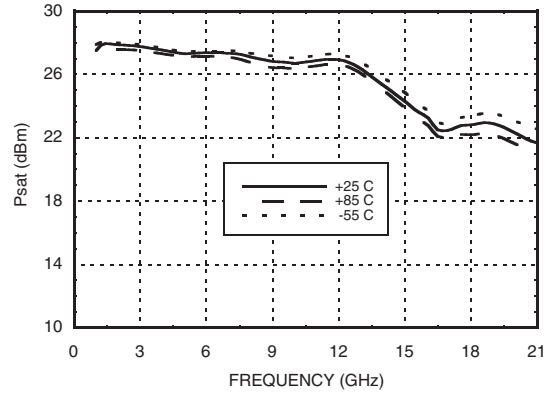
**WIDEBAND HIGH GAIN POWER AMPLIFIER
MODULE, 2 - 20 GHz**



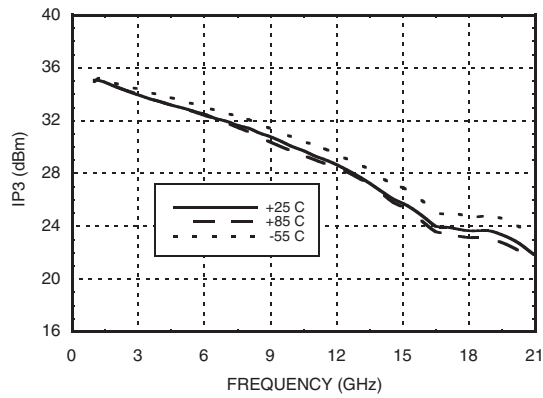
P1dB vs. Temperature



Psat vs. Temperature



Output IP3 vs. Temperature



Absolute Maximum Ratings

| | |
|--|----------------|
| RF Input Power (RFIN) | +23 dBm |
| Positive Bias Supply Voltage (+Vdc) | +17V Max |
| Negative Bias Supply (-Vdc) | -16V Min. |
| Thermal Resistance (at +Vdc = 12V, -Vdc = -4V, DC Power = 4.8 Watts) | 15.9 °C/W |
| Storage Temperature | -65 to +150 °C |
| Operating Temperature | -55 to +85 °C |

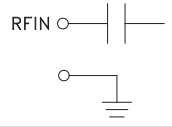
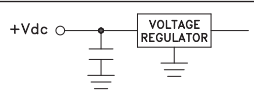
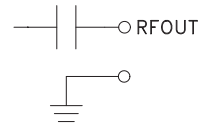
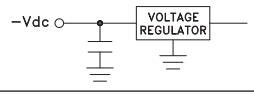



**ELECTROSTATIC SENSITIVE DEVICE
OBSERVE HANDLING PRECAUTIONS**

WIDEBAND HIGH GAIN POWER AMPLIFIER MODULE, 2 - 20 GHz



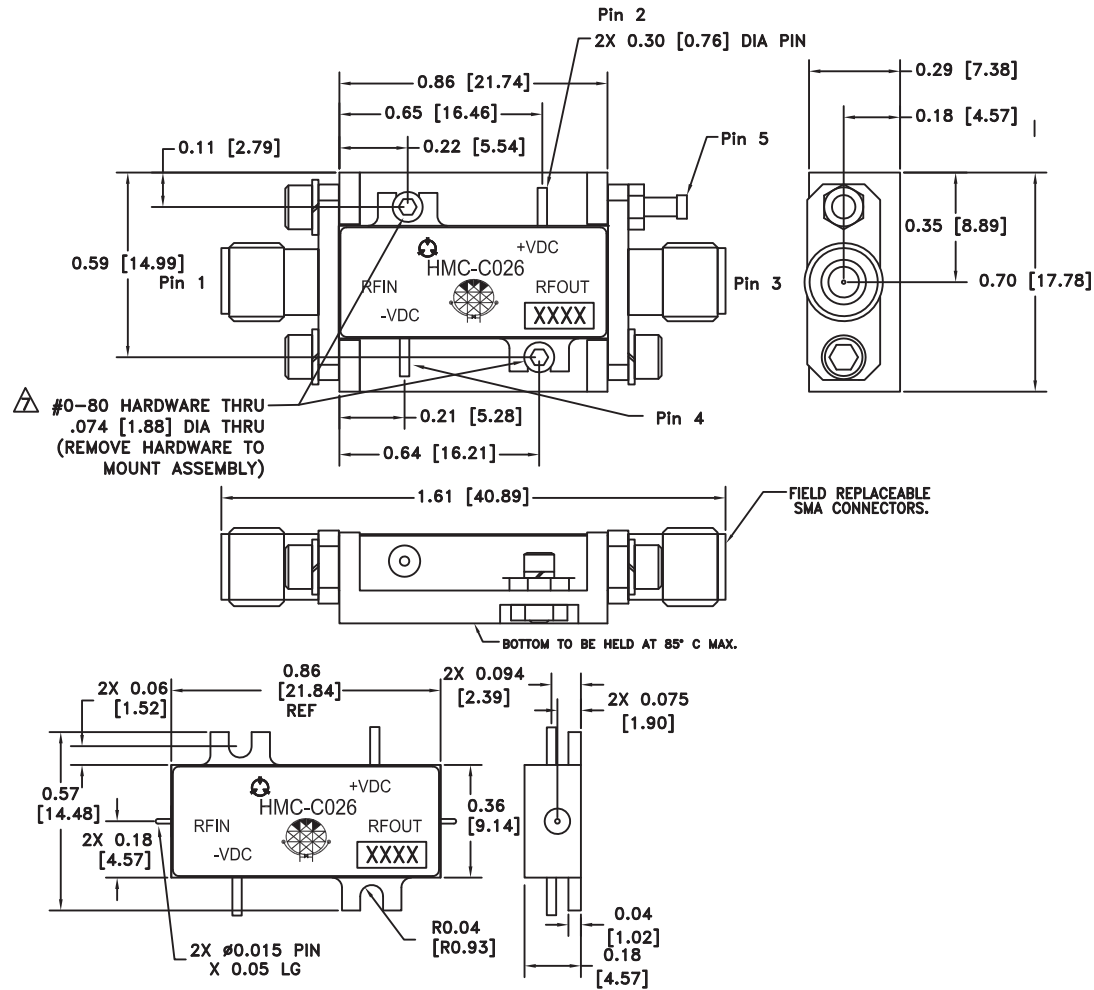
Pin Descriptions

| Pin Number | Function | Description | Interface Schematic |
|------------|-------------------|---|---|
| 1 | RFIN & RF Ground | RF input connector, SMA female, field replaceable. This pin is AC coupled and matched to 50 Ohms. |  |
| 2 | +Vdc | Positive power supply voltage for the amplifier. |  |
| 3 | RFOUT & RF Ground | RF output connector, SMA female. This pin is AC coupled and matched to 50 Ohms. |  |
| 4 | -Vdc | Negative power supply voltage for the amplifier. |  |
| 5 | GND | Power supply ground. |  |

**WIDEBAND HIGH GAIN POWER AMPLIFIER
MODULE, 2 - 20 GHz**



Outline Drawing



Package Information

| | |
|-------------------------------|-----------------------|
| Package Type | C-3B |
| Package Weight ^[1] | 12 gms ^[2] |
| Spacer Weight | N/A |

[1] Includes the connectors

[2] ±1 gms Tolerance

NOTES:

1. PACKAGE, LEADS, COVER MATERIAL: KOVAR™
2. SPACER MATERIAL: ALUMINUM
3. PLATING: ELECTROLYTIC GOLD 50 MICROINCHES MIN., OVER ELECTROLYTIC NICKEL 75 MICROINCHES MIN.
4. ALL DIMENSIONS ARE IN INCHES [MILLIMETERS].
5. TOLERANCES ±.005 [0.13] UNLESS OTHERWISE SPECIFIED.
6. FIELD REPLACEABLE SMA CONNECTORS. TENSOLITE 5602 - 5CCSF OR EQUIVALENT.

⚠ TO MOUNT MODULE TO SYSTEM PLATFORM REPLACE 0 - 80 HARDWARE WITH DESIRED MOUNTING SCREWS.

v03.1007

**WIDEBAND HIGH GAIN POWER AMPLIFIER
MODULE, 2 - 20 GHz****Notes:**